



General Multilayer Ceramic Capacitors



MLCC is an electronic part that temporarily stores an electrical charge and the most prevalent type of capacitor today. New technologies have enabled the MLCC manufacturers to follow the trend dictated by smaller and smaller electronic devices such as Cellular telephones, Computers, DSC, DVC

General Features

- Miniature Size
- Wide Capacitance and Voltage Range
- Tape & Reel for Surface Mount Assembly
- Low ESR

Applications

- General Electronic Circuit

Part Numbering

CL	<u> 10</u>	<u>B</u>	104	K	<u>B</u>	<u>8</u>	N	N	N	<u>C</u>
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- Samsung Multilayer Ceramic Capacitor
- 2 Size(mm)
- **3** Capacitance Temperature Characteristic
- 4 Nominal Capacitance
- 6 Capacitance Tolerance
- 6 Rated Voltage

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- 9 Samsung Control Code
- Reserved For Future Use
- Packaging Type

1 Samsung Multilayer Ceramic Capacitor

2 SIZE(mm)

Code	EIA CODE	Size(mm)
03	0201	0.6 × 0.3
05	0402	1.0 × 0.5
10	0603	1.6 × 0.8
21	0805	2.0 × 1.25
31	1206	3.2 × 1.6
32	1210	3.2 × 2.5
43	1812	4.5 × 3.2
55	2220	5.7 × 5.0





3 CAPACITANCE TEMPERATURE CHARACTERISTIC

Code		Temperature Characteristics				
С		COG	C△	0 ± 30 (ppm/ °C)		
Р		P2H	P△	-150 ± 60		
R		R2H	R△	-220 ± 60		
S	Class	S2H	S△	-330 ± 60	-55 ~ +125℃	
Т		T2H	T△	-470 ± 60		
U		U2J	U△	-750 ± 60		
L		S2L	S△	+350 ~ -1000		
Α		X5R	X5R	±15%	-55 ~ +85℃	
В	Class II	X7R	X7R	±15%	-55 ~ +125℃	
Х	Class II	X6S	X6S	±22%	-55 ~ +105℃	
F		Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃	

*** Temperature Characteristic**

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF
C∆	COG	COG	C0G	COG
P∆	-	P2J	P2H	P2H
R∆	-	R2J	R2H	R2H
S∆	-	S2J	S2H	S2H
T ∆	-	T2J	T2H	T2H
U∆	-	U2J	U2J	U2J

 $J: \pm 120PPM/^{\circ}C$, $H: \pm 60PPM/^{\circ}C$, $G: \pm 30PPM/^{\circ}C$

4 NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits.

The first and second digits identify the first and second significant figures of the capacitance.

The third digit identifies the multiplier. 'R' identifies a decimal point.

Example

Code	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 μF
104	100,000pF, 100nF, 0.1 μ F





O CAPACITANCE TOLERANCE

Code	Tolerance	Nominal Capacitance
Α	±0.05pF	
В	±0.1pF	
С	±0.25pF	Less than 10pF (Including 10pF)
D	± 0.5pF	(moldaing ropi)
F	±1pF	
F	±1%	
G	±2%	
J	±5%	More than 10pF
K	±10%	More than 10pF
М	±20%	
z	+80, -20%	

6 RATED VOLTAGE

Code	Rated Voltage	Code	Rated Voltage
R	4.0 V	D	200 V
Q	6.3V	E	250 V
Р	10V	G	500 V
O	16V	Н	630 V
Α	25V	I	1,000V
L	35V	J	2,000V
В	50V	К	3,000V
С	100V		





THICKNESS OPTION

Size	Code	Thickness(T)	Size	Code	Thickness(T)
0201(0603)	3	0.30±0.03		F	1.25±0.20
0402(1005)	5	0.50±0.05		н	1.6±0.20
0603(1608)	8	0.80±0.10	1812(4532)	ı	2.0±0.20
	Α	0.65±0.10		J	2.5±0.20
	С	0.85±0.10		L	3.2±0.30
0805(2012)	F	1.25±0.10		F	1.25±0.20
	Q	1.25±0.15		н	1.6±0.20
	Y	1.25±0.20	2220(5750)	ı	2.0±0.20
	С	0.85±0.15		J	2.5±0.20
1206(3216)	F	1.25±0.15		L	3.2±0.30
	н	1.6±0.20			
	F	1.25±0.20			
	Н	1.6±0.20			
1210(3225)	ı	2.0±0.20			
	J	2.5±0.20			
	V	2.5±0.30			

PRODUCT & PLATING METHOD

Code	Electrode	Termination	Plating Type
Α	Pd	Ag	Sn_100%
N	Ni	Cu	Sn_100%
G	Cu	Cu	Sn_100%

SAMSUNG CONTROL CODE

Code	Description of the code	Code	Description of the code
Α	Array (2-element)	N	Normal
В	Array (4-element)	Р	Automotive
С	High - Q	L	LICC





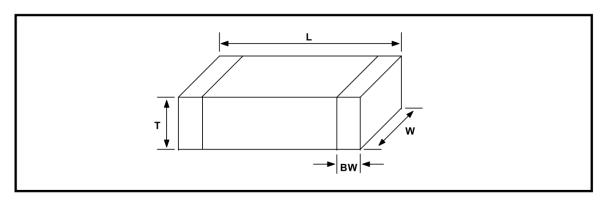
• RESERVED FOR FUTURE USE

Code	Description of the code
N	Reserved for future use

1 PACKAGING TYPE

Code	Packaging Type	Code	Packaging Type
В	Bulk	F	Embossing 13" (10,000EA)
Р	Bulk Case	L	Paper 13" (15,000EA)
С	Paper 7"	0	Paper 10"
D	Paper 13" (10,000EA)	S	Embossing 10"
Е	Embossing 7"		

APPEARANCE AND DIMENSION



CODE	EIA CODE		DIMENSION (mm)							
CODE	LIA CODE	L	w	T (MAX)	BW					
03	0201	0.6 ± 0.03	0.3 ± 0.03	0.33	0.15 ± 0.05					
05	0402	1.0 ± 0.05	0.5 ± 0.05	0.55	0.2 +0.15/-0.1					
10	0603	1.6 ± 0.1		0.9	0.3 ± 0.2					
21	0805	2.0 ± 0.1	1.25 ± 0.1	1.35	0.5 +0.2/-0.3					
24	1000	3.2 ± 0.15	1.6 ± 0.15	1.40	0.5 +0.2/-0.3					
31	1206	3.2 ± 0.2	1.6 ± 0.2	1.8	0.5 +0.3/-0.3					
20	1210	3.2 ± 0.3	2.5 ± 0.2	2.7	0.6 ± 0.3					
32	1210	3.2 ± 0.4	2.5 ± 0.3	2.8	0.6 ± 0.3					
43	1812 4.5 ± 0.4 3.2 ± 0.3		3.5	0.8 ± 0.3						
55	2220	5.7 ± 0.4	5.0 ± 0.4	3.5	1.0 ± 0.3					





NO	ITE	М	PER	FORMANCE	TEST	CONDITION		
1	Appea	rance	No Abnormal Exterior	Appearance	Through Microscope(×10)		
2	Insula Resist		10,000MΩ or 500 MΩ-μF v Rated Voltage is below 10,000MΩ or 100 MΩ-μF v	v 16V ;	Apply the Rated Voltage For 60 ~ 120 Sec.			
3	Withstanding No Dielectric Breakdown or Voltage Mechanical Breakdown				Class I: 300% of the Rated Voltage for 1~5 sec. Class II: 250% of the Rated Voltage for 1~5 sec. is applied with less than 50mA current			
					Capacitance	Frequency	Voltage	
		Class	Within the specifie	d tolerance	≤ 1,000 pF	1Mb ±10%		
	Capacita				>1,000 pF	1 kHz ±1 0%	0.5 ~ 5 Vrms	
4	nce				Capacitance	Frequency	Voltage	
		Class	Within the specifi	ed tolerance	≤ 10 μF	1 kHz ±1 0%	1.0±0.2Vrms	
		П			>10 <i>µ</i> F	120Hz±20%	0.5±0.1 Vrms	
			Capacitance ≥ 30pF :	Q ≥ 1,000	Capacitance	Frequency	Voltage	
5	Q	Class	· ·	: Q ≥ 400 +20C	≤ 1,000 pF	1Mb ±10%		
	I		(C	: Capacitance)	>1,000 pF	1 kHz ±1 0%	0.5 ~ 5 Vrms	
			1. Characteristic : A()	X5R), B(X7R), X(X6S)	Capacitance	Frequency	Voltage	
			Rated Voltage	Spec	∫ ≤ 10 <i>μ</i> F	1 klb ±1 0%	1.0±0.2Vrms	
			≥ 25V	0.025 max	>10 µF	120Hz±20%	0.5±0.1 Vrms	
			16V	0.035 max				
			10V	0.05 max	1			
			6.3V	0.05 max/ 0.10max*1	*1. 0201 C≥0.022uF, 0	402 C≥0.22uF,	0603 C≥2.2uF,	
				2. Characteristic : F(/5V)	0805 C≥4.7uF, 1206 C≥10uF, 1210 C≥22uF, 1812 C≥47uF, 2220 C≥100uF, All Low Profile Capacitors (P.16). *2 0603 C≥0.47uF, 0805 C≥1uF		C≥22uF,
6	Tan ∂	Class	Rated Voltage	Spec	*3. 0402 C≥0.033uF, 06			
		П	50V	0.05 max, 0.07max*2	All 0805, 1206 size		F	
			35V	0.07 max	*4 1210 C>6.8uF	,		
			25V	0.05 max/ 0.07 max* ³ / 0.09max* ⁴	*5 0402 C≥0.22uF			
	16V 0.		16V	0.09 max/ 0.125max*5	*6 All 1812 size			
			0.125 max/ 0.16max*6					
				0.16max				





NO	ITE	М	PERFORMANCE				TEST CONDITION	
INO	112			FERFOR	WANCE	0 "		
							shall be measured by the steps	
			Characte	ristics	Temp. Coefficient		following table.	
			Onaracte	1131103	(PPM/℃)	Step	Temp.(℃)	
			COC	3 <u> </u>	0 ± 30	1	25 ± 2	
		Class	PH		-150 ± 60	2	Min. operating temp. \pm 2	
			RH		-220 ± 60	3	25 ± 2	
		_	SH		-330 ± 60	4	Max. operating temp ± 2	
			ТН		-470 ± 60	5	25 ± 2	
			UL		-750 ± 120	(1) Class I	25 - 2	
			SL		+350 ~ -1000	` '	Coefficient shall be calculated from	
	Temperature							
7	Characteristics					the formula a		
,	of Capacitance						$ent = \frac{C2 - C1}{C1 \times \triangle T} \times 10^6 \text{ [ppm/°C]}$	
						C1; Capacita	ance at step 3	
			Characte	prietice	Capacitance Change	C2: Capacita		
		Class	Onaracte	51131105	with No Bias	△T: 60 °C (=8	35 ℃-25 ℃)	
			A(X5 B(X7	R)/ 7R)	± 15%	(2) CLASS II		
		-	X(Xe	SS)	± 22%	Capacitance	Change shall be calculated from the	
			F(Y5	(V)	+22% ~ -82%	formula as be	elow.	
						△C = <u>C2 -</u>	<u>C1</u> × 100(%)	
						C	1	
						C1; Capacita	ance at step 3	
						C2: Capacita	ance at step 2 or 4	
						Apply 500g.f * Pressure for 10±1 sec.		
						* 200g.f for 0201 case size.		
	Adhesive	Strenath	No Indicati	on Of Peel	ing Shall Occur On The			
8	of Term	-	Terminal E		ing chair coodi chi the			
							500g.f	
		Apperance	No mecha	nical dam	nage shall occur.	Bending limit		
						Test speed ;		
			Charact	teristics	Capacitance Change	'	t board at the limit point in 5 sec.,	
						Then measur	e capacitance.	
					Within \pm 5% or \pm 0.			
			Clas	ss I	5 pF whichever is		.20	
					larger		R=230	
9	9 Bending					50		
	Strength	Capacitance		A(X5R)/		1	_₩	
		Capacitance		B(X7R)/	Within ± 12.5%			
				X(X6S)		·		
			Class II			45±1	Bending limit	
				F(Y5V)	Within ±30%			





NO	IT	EM		PERF	ORMANCE		TEST CON	IDITION		
					ne terminal surface is to	Solder	Sn-3Ag-0.5	Cu 63Sn-37Pb		
				d newly, So or dissolve	metal part does not	Solder	245±5℃	235±5 ℃		
10	Solde	erability			7/	Temp. RMA Type				
						Dip Time				
						Pre-heating at 80~120°C for 10~30 sec.				
		Apperance	No mechanical damage shall occur.			Solder Ter	mperature : 270	±5℃		
			Charac	teristics	Capacitance Change		10±1 sec.			
					Within ±2.5% or			fully immersed and		
			Clas	s I	±0.25 pF whichever is larger	preheated as below :				
		Capacitance		A(X5R)/		STEP	TEMP.(℃)	TIME(SEC.)		
			Class II	B(X7R)	Within ±7.5%	1	80~100	60		
	Resistance to Soldering heat		Class II	X(X6S)	Within ±15%	2	150~180	60		
11			F Within ±20%				•	nbient condition for		
		Q	Capacitar	ice ≥30pF	: Q≥ 1000 : Q≥ 400+20×C	specified time* before measurement * 24 ± 2 hours (Class I)				
		(Class I)		< 30 pF	(C: Capacitance)		nours (Class II			
		Tan δ								
		(Class II)	Within the	specified	initial value					
		Insulation Resistance	Within the	Within the specified initial value						
		Withstanding								
		Voltage	Within the specified initial value							
		Appearance	No mecha	anical dam	age shall occur.					
			Charact	eristics	Capacitance Change					
					Within ±2.5% or	'	itor shall be su Motion having a	•		
			Clas	s l	±0.25 pF whichever is larger	Harmonic Motion having a total amplitude of 1.5mm changing frequency from 10Hz to 55H				
		Capacitance	Class	A(X5R)/ B(X7R)	Within ±5%	and back	to 10Hz In 1 m	in.		
12	Vibration		II	X(X6S)	Within ±10%			ch in 3 mutually		
	1651	Test		F(Y5V)	Within ±20%	perpendicu	lar directions			
		Q (Class I)	Within the	e specified	initial value					
		Tan δ (Class ${\mathbb H}$)	Within the	e specified	initial value					
		Insulation Resistance	Within the	e specified	initial value					





		Appearance	No mechanic	-1 -1					
				ai damage shaii	occur.	Temperature : 40±2 ℃			
			Charac	cteristics	Capacitance Change	Relative humidity : 90~95 %RH			
					Within ±5.0% or ±0.5pF	Duration time : 500 +12/-0 hr.			
		Capacitance	Cla	ss I	whichever is larger				
				A(X5R)/		Leave the capacitor in ambient			
			Class	B(X7R)/	Within ±12.5%	condition for specified time* before			
			П	X(X6S)		measurement.			
				F(Y5V)	Within ±30%	CLASSI : 24±2 Hr.			
		_	Capacitance ≥ 30pF : Q≥ 350		350	CLASSⅡ : 24±2 Hr.			
	Humidity	Q	10≤ Capacitance <30 pF : Q≥ 275 + 2.5×C						
13	(Steady	CLASS I	Capacitance	< 10pF : Q≥ 2	00 + 10×C (C: Capacitance)				
	State)		1. Characteris	stic: A(X5R),	2. Characteristic : F(Y5V)				
				B(X7R)					
			0.05max (16\	/ and over)	0.075max (25V and over)				
		Tan δ	0.075max (10	OV)	0.1max (16V, C<1.0μF)				
		CLASS II	0.075max		$0.125 \text{max} (16 \text{V}, \text{C} \ge 1.0 \mu\text{F})$				
			(6.3V excep	t Table 1)	0.15max (10V)				
			0.125max*		0.195max (6.3V)				
			(refer to Tabl	le 1)					
		Insulation	1 000 MC or	50MΩ·μF whichev	er is smaller				
		Resistance	1,000 3 01		or io omaion.				
		Appearance	No mechanic	al damage shall	occur.	Applied Voltage : rated voltage			
			Chara	cteristics	Capacitance Change	Temperature : 40±2 ℃ - Humidity : :90~95%RH			
			01-	T	Within ±5.0% or ±0.5pF	Duration Time: 500 +12/-0 Hr.			
			Class I		whichever is larger	Charge/Discharge Current : 50mA max.			
				A(X5R)/	Within ±12.5%				
		Capacitance		B(X7R)/	Within ±12.5%	Perform the initial measurement according to			
				X(X6S)	Within ±30%	Note1.			
			Class II		Within ±30%				
				F(Y5V)		Perform the final measurement according to			
				, ,	Within ±30%	Note2.			
	Moisture	Q	Capacitance	≥30pF : Q≥ 20	00				
14	Resistance	(Class I)	Capacitance	<30 pF : Q≥ 10	0 + 10/3×C (C: Capacitance)				
			1. Characteris	stic: A(X5R),	2. Characteristic : F(Y5V)	-			
				B(X7R)					
			0.05max (16\	/ and over)	0.075max (25V and over)				
			0.075max (10	OV)	0.1max (16V, C<1.0μF)				
		Tan δ	0.075max		$0.125 \text{max} (16 \text{V}, \text{C} \ge 1.0 \mu\text{F})$				
		(Class II)	(6.3V excep	t Table 1)	0.15max (10V)				
		(01035 11)	0.125max*		0.195max (6.3V)				
			(refer to Tab	ole 1)					
			X(X6S) 0.11n	nax (6.3V and b	elow)				
		Insulation							
		Resistance	500 MΩ or 25	iMΩ.μF whichever	is smaller.				
		Insulation	(refer to Table 1) X(X6S) 0.11max (6.3V and be		elow)				





NO	ITE	М		PERI	FORMANCE		TEST CONDIT	ION		
		Appearance	No mechanio	cal damage	shall occur.	1	oltage: 200%* of the	•		
			Charact	eristics	Capacitance Change		ime: 1000 +48/-0 H			
			QI.		Within ±3% or ±0.3pF,	Charge/Dis	charge Current: 50	ıA max.		
			Class	i 1	Whichever is larger	- * refer to table(3) : 150%/100% of the rated				
		Capacitance		A(X5R)/ B(X7R)	Within ±12.5%	voltage	1400(0) 1 100/4 100	,, , , , , , , , , , , , , , , , , , , ,		
			Class II	X(X6S)	Within ±25%	Perform the	e initial measuremen	t according to		
				E(VE) ()	Within ±30%	Note1 for	Class II			
				F(Y5V)	Within ±30%					
		Q	Capacitance	≥30pF : C	Q ≥ 350	Perform the	e final measurement	according to		
		(Class I)	10≤ Capaci	tance <30 p	$F : Q \ge 275 + 2.5 \times C$	Note2.		Ü		
	High	(Glass 1)	-		≥ 200 +10×C (C: Capacitance)					
15	Temperature		Characteri							
	Resistance		0.05max	B(X7R)	0.075max					
			(16V and o	vor)	(25V and over)					
			0.075max (10	,	0.1max(16V, C<1.0μF)					
			0.075max (10	J V)	$0.1125 \text{max} (16\text{V}, \text{ C} \ge 1.0 \mu\text{F})$					
		Tan δ	(6.3V excep	ot Table 1)	0.15max (10V)					
		(Class II)	0.125max*		0.195max (6.3V)					
			(refer to Ta	ble 1)						
			X(X6S) 0.11i	max (6.3V a	nd below)					
		Insulation Resistance	1,000 MΩ or	50MΩ·μF w hia	chever is smaller.					
		Appearance	No mechanio	cal damage	shall occur.	Capacitor	shall be subjected	d to 5 cycles.		
			Charact	eristics	Capacitance Change	Condition	for 1 cycle :			
			Class	. T	Within ±2.5% or ±0.25pF	Step	Temp.(℃)	Time(min.)		
				, 1	Whichever is larger	1	Min. operating	30		
		Capacitance	Class	A(X5R)/ B(X7R)/	Within ±7.5%	2	temp.+0/-3 25	2~3		
16	Temperature		II	X(X6S)	Within ±15%	3	Max. operating	20		
10	Cycle			F(Y5V)	Within ±20%		temp.+3/-0	30		
		Q (Class I)	Within the sp	pecified initia	al value	4 25 2~3 Leave the capacitor in ambient condition				
		Tan δ	Within the sp	pecified initia	al value	for specified time* before measurement * 24 ± 2 hours (Class I) 24 ± 2 hours (Class II)				
		Insulation Resistance	Within the sp	pecified initia	al value					





		Reco	ommended Sold	ering Method		
		Size	Temperature	_	Conc	lition
		inch (mm)	Characteristic	Capacitance	Flow	Reflow
		0201 (0603)	-	-	-	0
		0402 (1005)				
			Class I	-	0	0
		0603 (1608)	Class II	C < 1μF	0	0
			Class II	C ≥ 1 µF	-	0
	Recommended		Class I	•	0	0
18	Soldering Method	0805 (2012)	Class II	C < 4.7μF	0	0
	By Size & Capacitance		01033 11	$C \geq 4.7 \mu F$	-	0
	by ones a supusinarios		Array	-	-	0
			Class I	-	0	0
		1006 (2016)	Class II	C < 10μF	0	0
		1206 (3216)	Class II	C ≥ 10 <i>μ</i> F	1	0
			Array	-	-	0
		1210 (3225)				0
		1808 (4520)				0
		1812 (4532)	-	-	-	0
		2220 (5750)				0

Note1. Initial Measurement For Class $\boldsymbol{\mathbb{I}}$

Perform the heat treatment at 150%+0/-10% for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement. Then perform the measurement.

Note2. Latter Measurement

1. CLASS I

Leave the capacitor in ambient condition for 24±2 hours before measurement

Then perform the measurement.

2. Class ${\mathbb I}$

Perform the heat treatment at $150\,\text{°C} + 0/-10\,\text{°C}$ for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement. Then perform the measurement.

*Table1.

Tan ∂	0.125max*					
Class Ⅱ A(X5R), B(X7R)	0201 C \geq 0.022 μ F 0402 C \geq 0.22 μ F 0603 C \geq 2.2 μ F 0805 C \geq 4.7 μ F 1206 C \geq 10.0 μ F 1210 C \geq 22.0 μ F 1812 C \geq 47.0 μ F 2220 C \geq 100.0 μ F All Low Profile Capacitors (P.16).					

*Table2.

High Tem	perature Resistance test
⊿C (Y5V)	± 30%
	0402 C \geq 0.47 μ F
	0603 C ≥ 2.2μF
Class II	0805 C ≥ 4.7μF
F(Y5V)	1206 C $\geq 10.0 \mu F$
F(15V)	1210 C \geq 22.0 μ F
	1812 C \geq 47.0 μ F
	2220 C $\geq 100.0 \mu F$
	,

*Table3.

	High Temperature Resistance test							
Applied Voltage	100% of the rated voltage	150% of the rated voltage						
Class II A(X5R), B(X7R), X(X6S), F(Y5V)	0201 C $\geq 0.1 \mu F$ 0402 C $\geq 1.0 \mu F$ 0603 C $\geq 4.7 \mu F$ 0805 C $\geq 22.0 \mu F$ 1206 C $\geq 47.0 \mu F$ 1210 C $\geq 100.0 \mu F$ All Low Profile Capacitors (P.16).	0201 C $\geq 0.022 \mu F$ 0402 C $\geq 0.47 \mu F$ 0603 C $\geq 2.2 \mu F$ 0805 C $\geq 4.7 \mu F$ 1206 C $\geq 10.0 \mu F$ 1210 C $\geq 22.0 \mu F$ 1812 C $\geq 47.0 \mu F$ 2220 C $\geq 100.0 \mu F$						

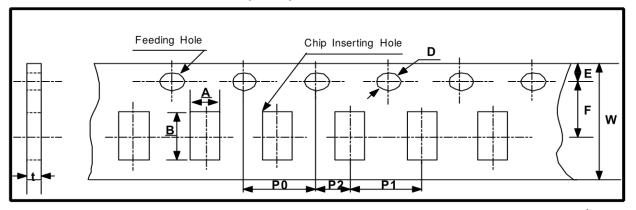
Note3. All Size In Reliability Test Condition Section is "inch"





PACKAGING

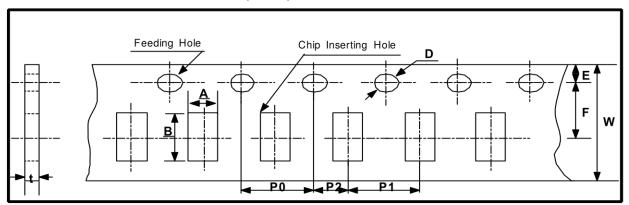
● CARDBOARD PAPER TAPE (4mm)



unit: mm

	mbol ype	Α	В	w	F	E	P1	P2	P0	D	t
D i m	0603 (1608)	1.1 ±0.2	1.9 ±0.2								
e n s	0805 (2012)	1.6 ±0.2	2.4 ±0.2	8.0 ±0.3	3.5 ±0.05	1.75 ±0.1	4.0 ±0.1	2.0 ±0.05	4.0 ±0.1	Ф1.5 +0.1/-0	1.1 Below
i o n	1206 (3216)	2.0 ±0.2	3.6 ±0.2								

● CARDBOARD PAPER TAPE (2mm)



unit : mm

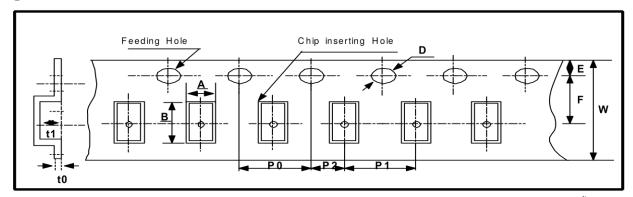
S	ymbol Type	Α	В	w	F	E	P1	P2	P0	D	t
D i m e	0201 (0603)	0.38 ±0.03	0.68 ±0.03	8.0	3.5	1.75	2.0	2.0	4.0	Ф1.5	0.37 ±0.03
n s i o n	0402 (1005)	0.62 ±0.04	1.12 ±0.04	±0.3	±0.05	±0.1	±0.05	±0.05	±0.1	+0.1/-0.03	0.6 ±0.05





PACKAGING

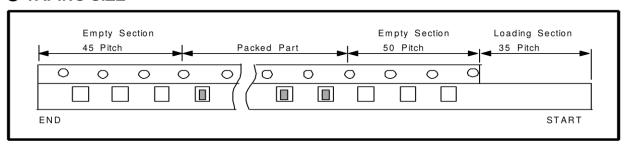
● EMBOSSED PLASTIC TAPE



unit: mm

Sy	m bol	Α	В	w	F	Е	P1	P 2	Р0	D	t1	t0
Т	ype	, ,				_			. •			
	0805 (2012)	1.45 ±0.2	2.3 ±0.2									
P	1206 (3216)	1.9 ±0.2	3.5 ±0.2	8.0 ±0.3	3.5 ±0.05		4.0 ±0.1				2.5 max	
m e	1210 (3225)	2.9 ±0.2	3.7 ±0.2			1.75		2.0	4.0	Ф1.5 +0.1/-0		0.6
n s i	1808 (4520)	2.3 ±0.2	4.9 ±0.2			±0.1		±0.05	±0.1	+0.17-0		Below
o n	1812 (4532)	3.6 ±0.2	4.9 ±0.2	12.0 ±0.3	5.60 ±0.05		8.0 ±0.1				3.8 m a x	
	2220 (5750)	5.5 ±0.2	6.2 ±0.2									

TAPING SIZE



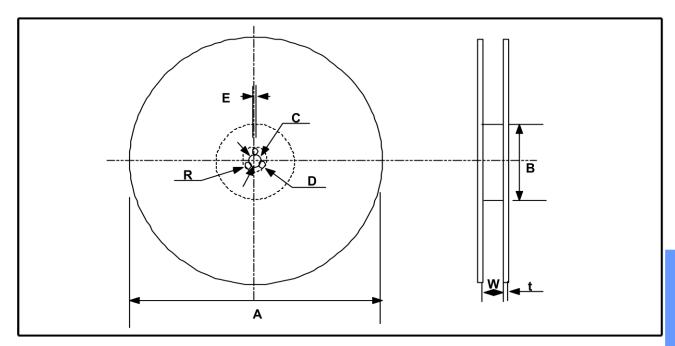
Type	Symbol	Size	Cardboard Paper Tape	Symbol	Size	Embossed Plastic Tape
		0201(0603)	10,000		All Size ≤ 3216 1210(3225),1808(4520) (t≤1.6mm)	2,000
7" Reel	С	0402(1005)	10,000	E	1210(3225)(t≥2.0 m m)	1,000
		OTHERS	4,000		1808(4520)(t≥2.0 m m)	1,000
10" Reel	0	-	10,000	-	-	-
	D	0402(1005)	50,000		All Size ≤ 3216 1210(3225),1808(4520) (t<1.6mm)	10,000
		OTHERS	10,000		$1210(3225)(1.6 \le t < 2.0 \text{ m m}) \\ 1206(3216)(1.6 \le t)$	8,000
13" Reel		0603(1608)	10,000 or 15,000	F	1210(3225),1808(4520) (t≥2.0mm)	4,000
	L 0805(2012) 15,000 or (t≤0.85mm) 10,000(Option)		1812(4532)(t≤2.0 m m)	4,000		
		1206(3216) (t≤0.85mm)	10,000		1812(4532)(t>2.0mm) 5750(2220)	2,000





PACKAGING

• REEL DIMENSION



unit : mm

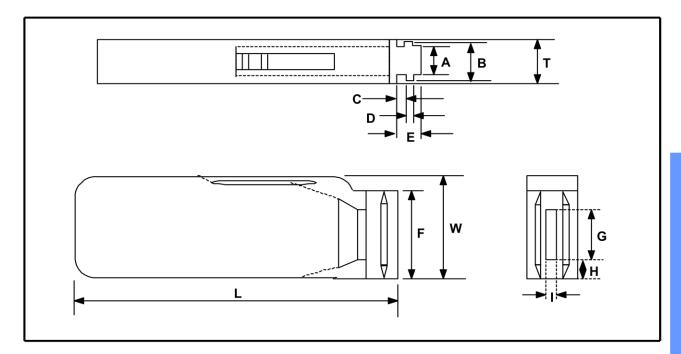
Symbol	A	В	С	D	E	w	t	R
7" Reel	ф180+0/ -3	φ60+1/ -3	410 +0.0	05 ± 0. 5	20+05	0+15	1.2±0.2	1.0
13" Ree	φ330±2.0	ф80+1/ -3	φ13±0.3	25±0.5	2.0±0.5	9±1.5	2.2±0.2	1.0





BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



unit: mm

Symbol	Α	В	Т	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	3.0+0.2/-0

Symbol	F	W	G	Н	L	I
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7±0.35	110±0.7	5±0.35

QUANTITY OF BULK CASE PACKAGING

unit : pcs

6:	0402/4005)	0002/4000	0805(2012)
Size	0402(1005)	0603(1608)	T=0.65mm	T=0.85mm
Quantity	50,000	10,000 or 15,000	10,000	5,000 or 10,000

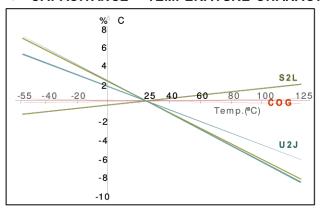


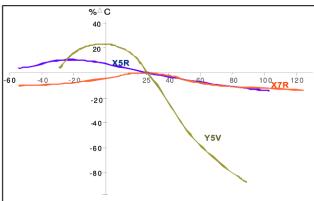


APPLICATION MANUAL

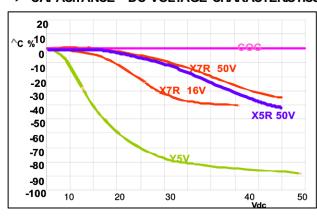
• ELECTRICAL CHARACTERISTICS

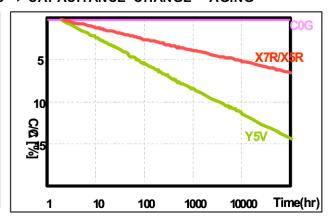
► CAPACITANCE - TEMPERATURE CHARACTERISTICS



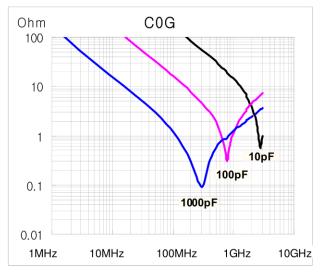


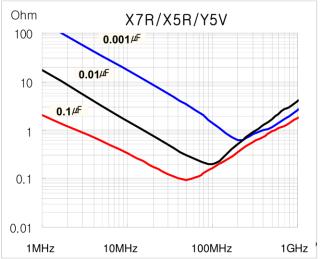
► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





▶ IMPEDANCE - FREQUENCY CHARACTERISTICS









STORAGE CONDITION

▶ Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40 °C and 70%, respectively.

Guaranteed storage period is within 6 months from the outgoing date of delivery.

Corrosive Gases

Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

▶ Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

DESIGN OF LAND PATTERN

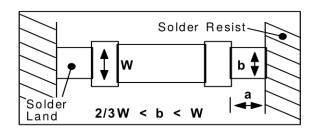
When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor.

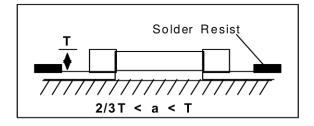
The amount of solder at the end terminations has a direct effect on the crack.

The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently.

Use the following illustrations as guidelines for proper land design.

Recommendation of Land Shape and Size.









ADHESIVES

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

► Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

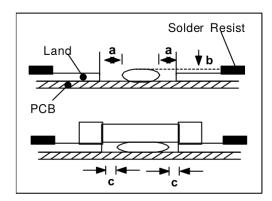
They should not spread or run when applied to the circuit board.

They should harden quickly. They should not corrode the circuit board or chip material.

They should be a good insulator. They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

▶ Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.



		unit : mm
Туре	21	31
а	0.2 min	0.2 min
b	70~100 µm	70~100 µm
С	> 0	> 0

Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at $160\,^{\circ}$ C or less, within 2 minutes or less.

MOUNTING

▶ Mounting Head Pressure

Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.

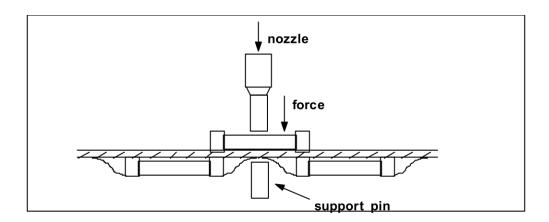




▶ Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side,

it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



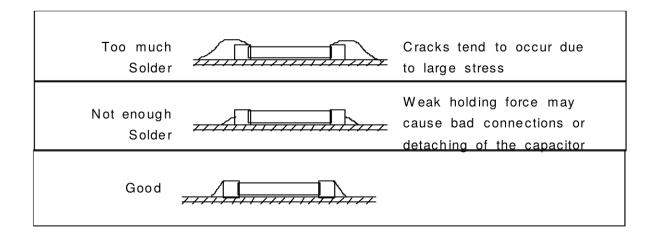
▶ Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors.

The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor.

Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

Amount of Solder







▶ Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference($\triangle T$) must be less than 100 $^{\circ}$ C

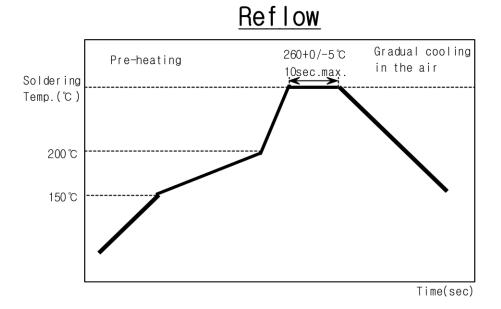
▶ Cleaning

If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

▶ Notes for Separating Multiple, Shared PC Boards.

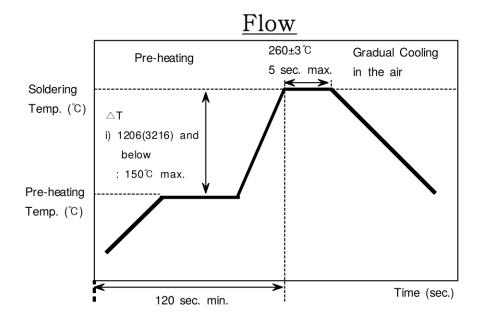
A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending often circuit board.

► Recommended Soldering Profile









Soldering Iron

Variation of Temp.	Soldering	Pre-heating	Soldering	Cooling
	Temp (°C)	Time (Sec)	Time(Sec)	Time(Sec)
△T≤130	300±10℃max	≥ 60	≤ 4	-

Condition of Iron facilities				
Wattage	Tip Diameter	Soldering Time		
20W Max	3mm Max	4 Sec Max		

^{*} Caution - Iron Tip Should Not Contact With Ceramic Body Directly.